

# RJK5003DPD

# Silicon N Channel Power MOS FET High Speed Power Switching Use

REJ03G0580-0200 Rev.2.00 Mar 14, 2006

#### **Features**

• V<sub>DSS</sub>: 500 V

•  $R_{DS(on)}$ : 1.5  $\Omega$  (MAX.)

• I<sub>D</sub>: 5 A

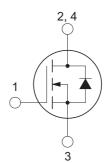
• Surface mount package (MP-3A)

#### **Outline**

RENESAS Package code: PRSS0004ZA-A

(Package name : MP-3A)





- 1. Gate
- 2. Drain
- 3. Source
- 4. Drain

#### **Applications**

• Lighting ballast, SMPS, etc.

## **Maximum Ratings**

 $(Tc = 25^{\circ}C)$ 

Parameter	Symbol	Ratings	Unit	Conditions
Drain to source voltage	V <sub>DSS</sub>	500	V	V <sub>GS</sub> = 0 V
Gate to source voltage	$V_{GSS}$	±30	V	$V_{DS} = 0 V$
Drain current	I <sub>D</sub>	5	Α	
Drain Peak current	I <sub>D (pulse)</sub> Note1	20	А	
Avalanche current	I <sub>AP</sub>	5	А	L = 200 μH
Channel dissipation	Pch	62.5	W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	
Channel to case thermal impedance	$\theta_{ch-c}$	2.0	°C/W	Channel to case

Note: 1. Pulse width limited by safe operating area.

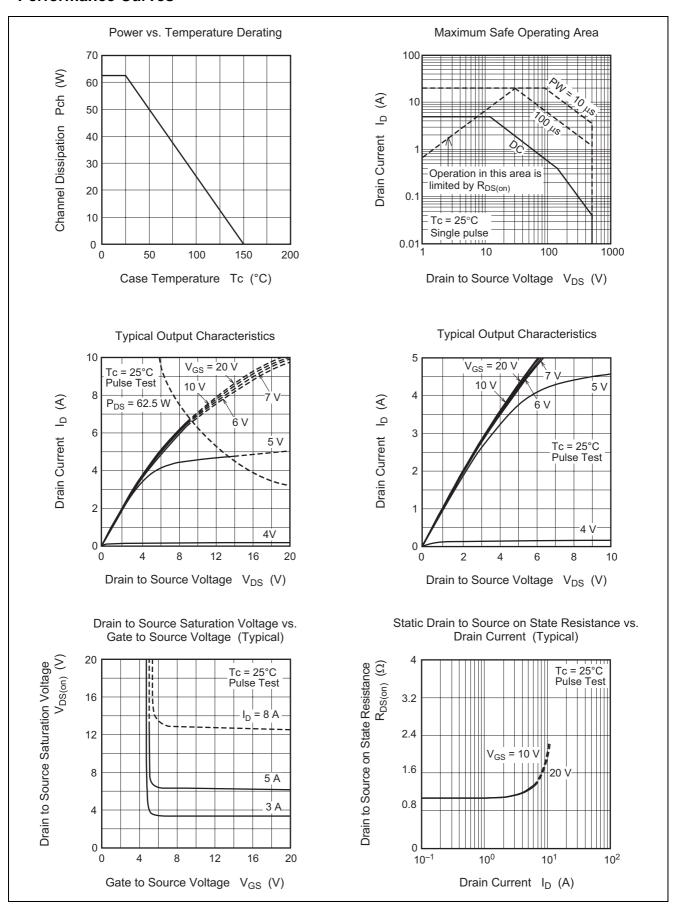
# **Electrical Characteristics**

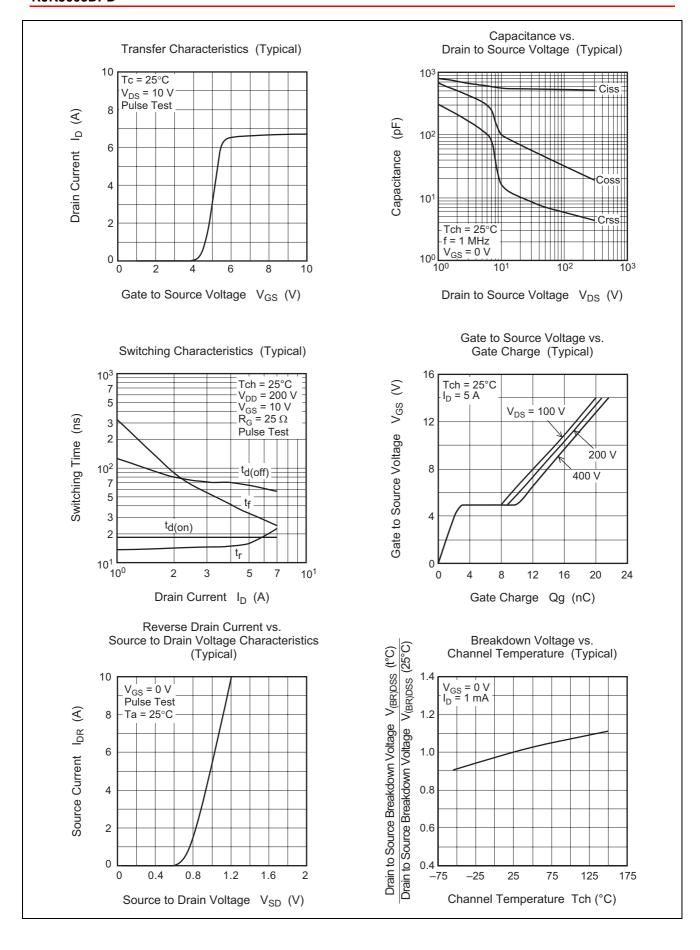
 $(Tch = 25^{\circ}C)$ 

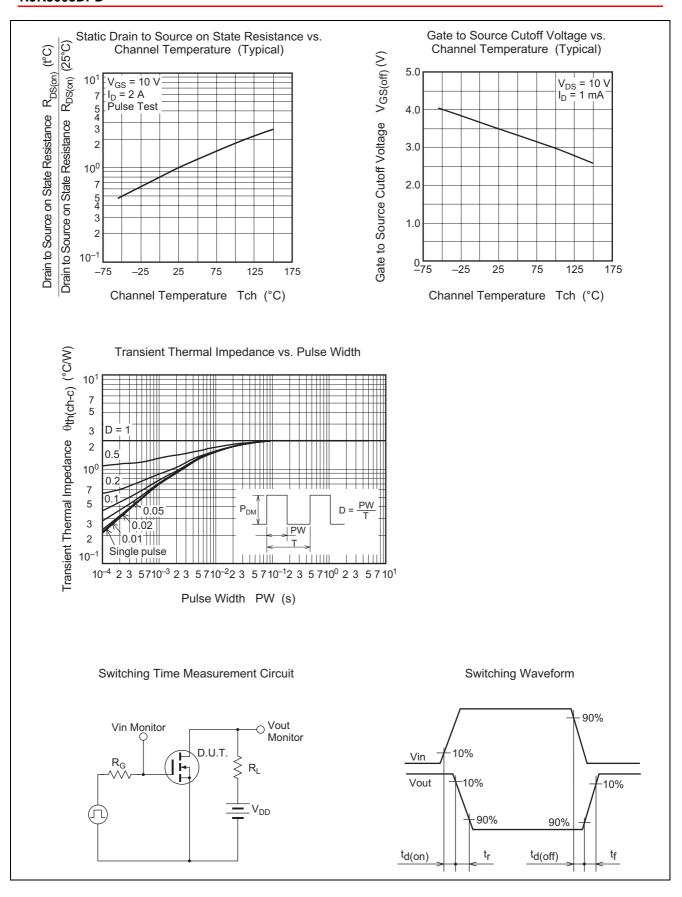
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	500	_	_	V	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	mA	$V_{DS} = 500 \text{ V}, V_{GS} = 0 \text{ V}$
Gate to source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$
Gate to source cutoff voltage	$V_{GS(off)}$	3.0	3.5	4.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state	R <sub>DS(on)</sub>	_	1.3	1.5	Ω	I <sub>D</sub> = 2 A, V <sub>GS</sub> = 10 V <sup>Note2</sup>
resistance						
Input capacitance	Ciss	_	550		pF	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$
Output capacitance	Coss	_	60	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	10	_	pF	
Turn-on delay time	t <sub>d(on)</sub>	_	20	_	ns	$V_{DD} = 200 \text{ V}, I_D = 2 \text{ A},$
Rise time	t <sub>r</sub>	_	20	_	ns	$V_{GS} = 10 \text{ V}$ $R_G = 25 \Omega$
Turn-off delay time	t <sub>d(off)</sub>	_	60	_	ns	
Fall time	t <sub>f</sub>	_	25	_	ns	
Body-drain diode forward voltage	$V_{DF}$	_	1.0	1.5	V	$I_F = 2 A$ , $V_{GS} = 0 V^{Note2}$

Note: 2. Pulse test

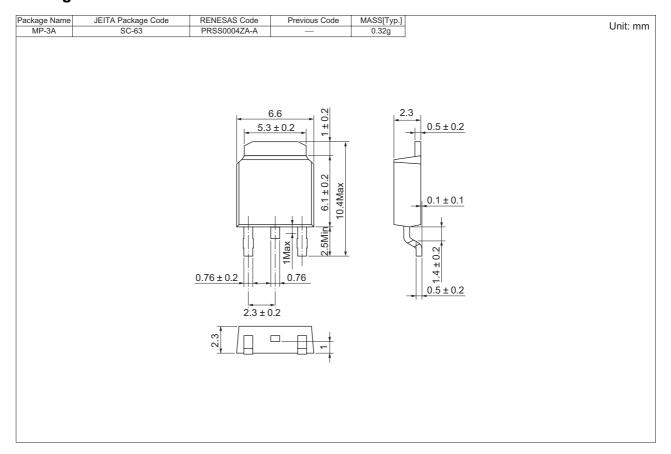
#### **Performance Curves**







# **Package Dimensions**



## **Order Code**

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Surface-mounted type	Taping	3000	Type name - 00 - direction (J or Q) - 2	RJK5003DPD-00-J2

Note: It is the case of a standard. In addition, please confirm the packing specification for every product about the contents of packing.

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